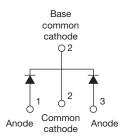


Vishay Semiconductors

Hyperfast Rectifier, 2 x 4 A FRED Pt®



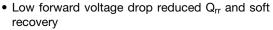




PRODUCT SUMMARY							
Package	D-PAK (TO-252AA)						
I _{F(AV)}	2 x 4 A						
V_{R}	200 V						
V _F at I _F	0.95 V						
t _{rr} (typ.)	23 ns						
T _J max.	175 °C						
Diode variation	Common cathode						

FEATURES

- Hyperfast recovery time
- 175 °C max. operating junction temperature
- · Output rectification freewheeling





HALOGEN

FREE

- Low leakage current
- Compliant to RoHS Directive 2002/95/EC
- Halogen-free according to IEC 61249-2-21 definition
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C

DESCRIPTION/APPLICATIONS

State of the art hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC boost stage in the AC/DC section of SMPS inverters or as freewheeling diodes. Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS									
PARAMETER SYMBOL TEST CONDITIONS VALUES UNIT									
Peak repetitive reverse voltage	V_{RRM}		200	V					
Average rectified forward current	I _{F(AV)}	T _C = 164 °C	8	۸					
Non-repetitive peak surge current per leg	I _{FSM}	T _J = 25 °C	80	A					
Operating junction and storage temperatures	T _J , T _{Stg}		- 65 to 175	°C					

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)									
PARAMETER	MIN.	TYP.	MAX.	UNITS					
Breakdown voltage, blocking voltage	V _{BR} , V _R	Ι _R = 100 μΑ	200	-	-				
Forward voltage per leg		I _F = 4 A	-	0.87	0.95				
	V _F			0.95	1.10	V			
				0.71	0.80				
		I _F = 8 A, T _J = 150 °C	- 0.8 1.0						
	I _R	$V_R = V_R$ rated	-	-	4				
Reverse leakage current per leg		$T_J = 125 ^{\circ}\text{C}, V_R = V_R \text{ rated}$	-	-	40	μΑ			
		T _J = 150 °C, V _R = V _R rated	-	-	80				
Junction capacitance per leg	C _T	V _R = 200 V	-	17	-	pF			
Series inductance	L _S	Measured lead to lead 5 mm from package body	-	8	-	nH			

Document Number: 93261 Revision: 31-Mar-11

VS-8CWH02FN-M3

Vishay Semiconductors Hyperfast Rectifier, 2 x 4 A FRED Pt®



DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)									
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS		
		$I_F = 1 A, dI_F/dt = 10$	00 A/μs, V _R = 30 V	-	23	27			
Reverse recovery time Peak recovery current	t _{rr}	T _J = 25 °C		-	20	-	ns A nC		
		T _J = 125 °C	$I_F = 4 \text{ A}$ $dI_F/dt = 200 \text{ A/}\mu\text{s}$ $V_R = 160 \text{ V}$	-	27	-			
	I _{RRM}	T _J = 25 °C		-	2	-			
		T _J = 125 °C		-	3.4	-			
Reverse recovery charge	0	T _J = 25 °C		=	20	-			
	Q_{rr}	T _J = 125 °C		-	46	-			

THERMAL - MECHANICAL SPECIFICATIONS										
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS				
Maximum junction and storage temperature range	T _J , T _{Stg}		- 65	-	175	°C				
Thermal resistance, per leg			-	2.7	3.2	°C/W				
junction to case per device	R_{thJC}		-	1.35	1.6	C/VV				
A no vovimente vuoi alet				0.3		g				
Approximate weight				0.01		OZ.				
Marking device		Case style D-PAK (TO-252AA)		8CWF	102FN					



Hyperfast Rectifier, 2 x 4 A FRED Pt® Vishay Semiconductors

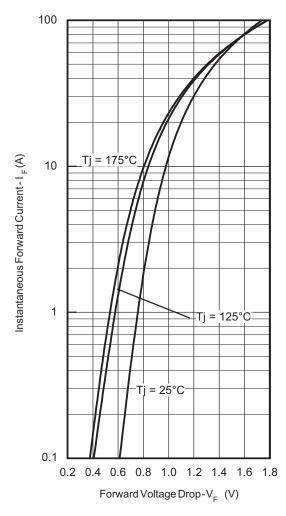


Fig. 1 - Typical Forward Voltage Drop Characteristics

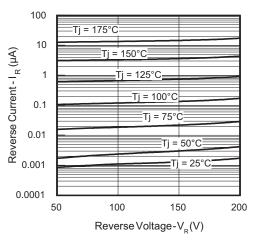


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

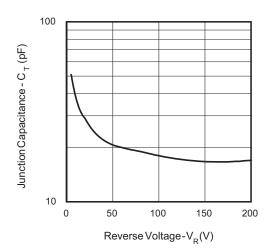


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

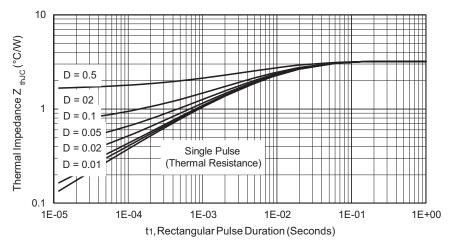


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics

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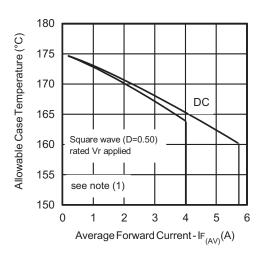


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

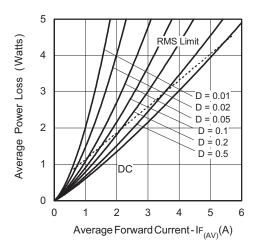


Fig. 6 - Forward Power Loss Characteristics

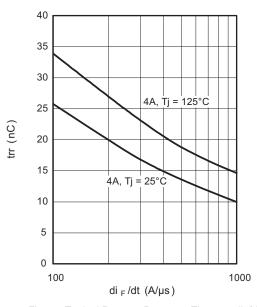


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

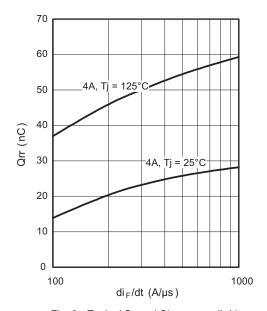


Fig. 8 - Typical Stored Charge vs. dl_F/dt

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; Pd = Forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6); Pd_{REV} = Inverse power loss = $V_{R1} \times I_R (1 - D)$; I_R at V_{R1} = Rated V_R



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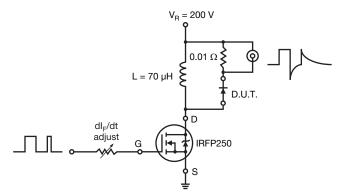
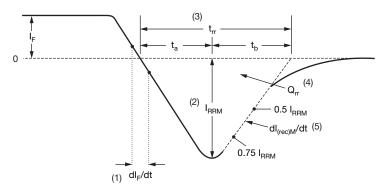


Fig. 9 - Reverse Recovery Parameter Test Circuit



- (1) dl_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) $t_{\rm rr}$ reverse recovery time measured from zero crossing point of negative going $I_{\rm F}$ to point where a line passing through 0.75 $I_{\rm RRM}$ and 0.50 $I_{\rm RRM}$ extrapolated to zero current.
- (4) \mathbf{Q}_{rr} area under curve defined by \mathbf{t}_{rr} and \mathbf{I}_{RRM}

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) $dl_{(rec)M}/dt$ - peak rate of change of current during t_b portion of t_{rr}

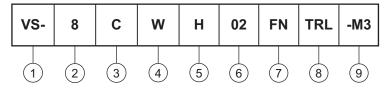
Fig. 10 - Reverse Recovery Waveform and Definitions

Vishay Semiconductors Hyperfast Rectifier, 2 x 4 A FRED Pt®



ORDERING INFORMATION TABLE

Device code



- Vishay Semiconductors product
- Current rating (8 = 8 A)
- Circuit configuration:
 - C = Common cathode
- Package identifier:
 - W = D-PAK
- H = Hyperfast recovery
- Voltage rating (02 = 200 V)
- FN = TO-252AA
- None = Tube
 - TR = Tape and reel
 - TRL = Tape and reel (left oriented)
 - TRR = Tape and reel (right oriented)
- 9 Environmental digit:
 - -M3 = Halogen-free, RoHS compliant and terminations lead (Pb)-free

ORDERING INFORMATION (Example)									
PREFERRED P/N QUANTITY PER T/R MINIMUM ORDER QUANTITY PACKAGING DESCRIPT									
VS-8CWH02FN-M3	75	3000	Antistatic plastic tube						
VS-8CWH02FNTR-M3	2000	2000	13" diameter reel						
VS-8CWH02FNTRL-M3	3000	3000	13" diameter reel						
VS-8CWH02FNTRR-M3	3000	3000	13" diameter reel						

LINKS TO RELATED DOCUMENTS						
Dimensions <u>www.vishay.com/doc?95016</u>						
Part marking information	www.vishay.com/doc?95176					
Packaging information	www.vishay.com/doc?95033					
SPICE model	www.vishay.com/doc?95375					



Vishay Semiconductors

INCHES

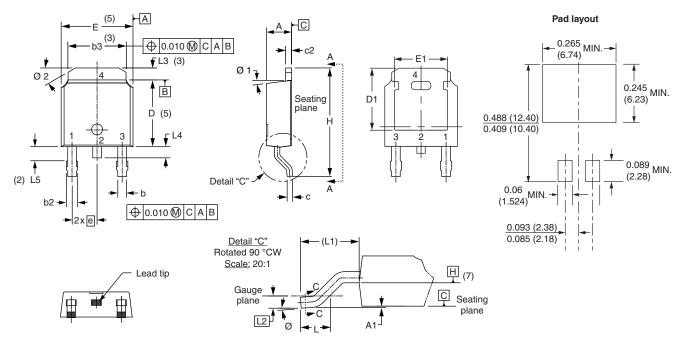
MIN.

MAX.

NOTES

D-PAK (TO-252AA)

DIMENSIONS in millimeters and inches



SYMBOL	MILLIN	IETERS	INC	HES	NOTES	SYMBOL	MILLIN	IETERS			
STIVIBUL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	NOTES	NOTES	STIVIDOL	MIN.	MAX.
Α	2.18	2.39	0.086	0.094		е	2.29	BSC			
A1	-	0.13	-	0.005		Н	9.40	10.41			
b	0.64	0.89	0.025	0.035		L	1.40	1.78			
b2	0.76	1.14	0.030	0.045		L1	2.74	BSC			
b3	4.95	5.46	0.195	0.215	3	L2	0.51	BSC			
С	0.46	0.61	0.018	0.024		L3	0.89	1.27			
c2	0.46	0.89	0.018	0.035		L4	-	1.02			
D	5.97	6.22	0.235	0.245	5	L5	1.14	1.52			
D1	5.21	-	0.205	-	3	Ø	0°	10°			
Е	6.35	6.73	0.250	0.265	5	Ø1	0°	15°			
E1	4.32	-	0.170	-	3	Ø2	25°	35°			

	е	2.29 BSC		0.090 BSC		
	Н	9.40	10.41	0.370	0.410	
	L	1.40	1.78	0.055	0.070	
	L1	2.74	2.74 BSC		0.108 REF.	
	L2	0.51	BSC	0.020	BSC	
	L3	0.89	1.27	0.035	0.050	3
	L4	-	1.02	-	0.040	
	L5	1.14	1.52	0.045	0.060	2
	Ø	0°	10°	0°	10°	
	Ø1	0°	15°	0°	15°	
	Ø2	25°	35°	25°	35°	

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- Lead dimension uncontrolled in L5
- (3) Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad
- Section C C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip
- Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- Dimension b1 and c1 applied to base metal only
- (7) Datum A and B to be determined at datum plane H
- Outline conforms to JEDEC outline TO-252AA



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Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

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Revision: 02-Oct-12 Document Number: 91000

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